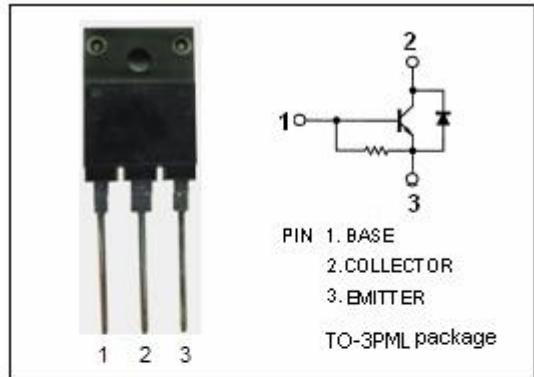


Silicon NPN Power Transistor

DESCRIPTION

- Collector-Emitter Breakdown Voltage-
: $V_{(BR)CEO} = 50V$ (Min)
- Low Collector Saturation Voltage-
: $V_{CE(sat)} = 0.5V$ (Max)@ $I_C = 5A$

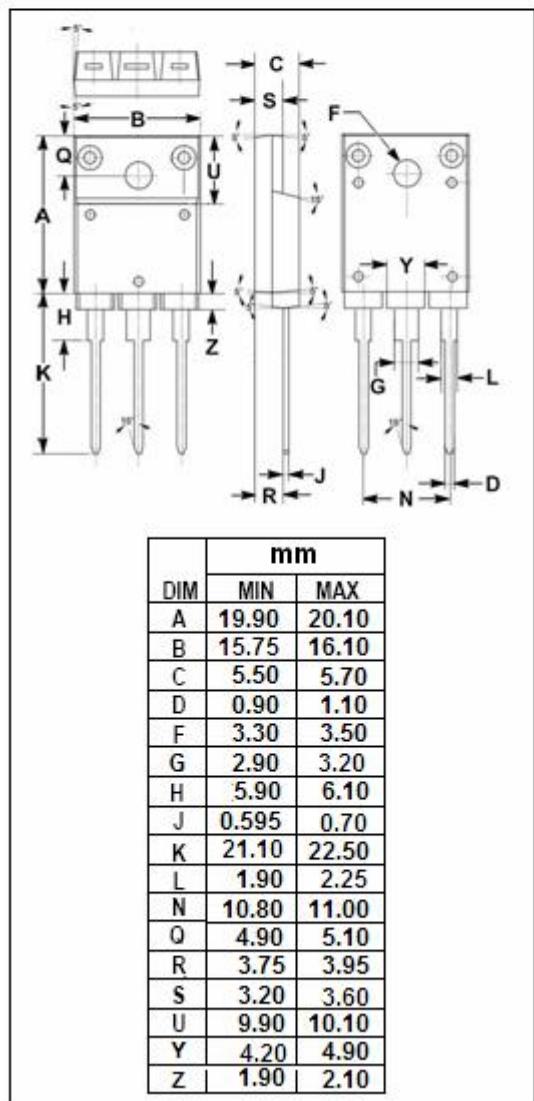


APPLICATIONS

- Designed for DC-DC converter, emergency lighting inverter and general purpose applications

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

| SYMBOL | PARAMETER | VALUE | UNIT |
|-----------|--|---------|------|
| V_{CBO} | Collector-Base Voltage | 100 | V |
| V_{CEO} | Collector-Emitter Voltage | 50 | V |
| V_{EBO} | Emitter-Base Voltage | 15 | V |
| I_C | Collector Current-Continuous | 15 | A |
| I_{CP} | Collector Current-Peak | 25 | A |
| I_B | Base Current-Continuous | 4 | A |
| P_c | Collector Power Dissipation @ $T_c=25^\circ C$ | 60 | W |
| T_J | Junction Temperature | 150 | °C |
| T_{stg} | Storage Temperature Range | -55~150 | °C |



Ordering Information

| Product | Package | Packaging |
|-------------|---------|-----------|
| 2SC4131T5TL | TO-3PML | Tube |



2SC4131T5TL

ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | TYP. | MAX | UNIT |
|----------------------|--------------------------------------|---|-----|------|-----|------|
| V _{(BR)CEO} | Collector-Emitter Breakdown Voltage | I _C = 25mA; I _B = 0 | 50 | | | V |
| V _{CE(sat)} | Collector-Emitter Saturation Voltage | I _C = 5A; I _B = 80mA | | | 0.5 | V |
| V _{BE(sat)} | Base-Emitter Saturation Voltage | I _C = 5A; I _B = 80mA | | | 1.2 | V |
| I _{CBO} | Collector Cutoff Current | V _{CB} = 100V ; I _E = 0 | | | 10 | µ A |
| I _{EBO} | Emitter Cutoff Current | V _{EB} = 15V ; I _C = 0 | | | 10 | µ A |
| h _{FE} | DC current gain | I _C = 5A ; V _{CE} = 1V | 60 | | 360 | |
| f _r | Current-Gain—Bandwidth Product | I _E = -1A ; V _{CE} = 12V | | 18 | | MHz |
| C _{OB} | Output Capacitance | I _E =0 ; V _{CB} = 10V; f _{test} = 1.0MHz | | 210 | | pF |

Switching times

| | | | | | |
|------------------|--------------|--|-----|--|-----|
| t _{on} | Turn-on Time | I _C = 5A , I _{B1} = 80mA; I _{B2} = 80mA R _L = 4 Ω ; V _{CC} = 20V | 0.5 | | µ s |
| t _{stg} | Storage Time | | 2.0 | | µ s |
| t _f | Fall Time | | 0.4 | | µ s |

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[C4460](#) [SBC846BLT3G](#) [2SA1419T-TD-H](#) [2SA1721-O\(TE85L,F\)](#) [2SA1727TLP](#) [2SA2126-E](#) [2SB1202T-TL-E](#) [2SB1204S-TL-E](#) [2SC5488A-TL-H](#)
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